## NSN 5961-01-054-5810

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-054-5810 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Diameter:** 0.667 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.669 inches and 0.688 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, peak **Current Rating Per Characteristic:** 300.00 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug **Specification Data:** 81349-mil-s-19500/308 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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